

NPN Darlington Transistor BC517

Features

- This Device is Designed for Applications Requiring Extremely High Current Gain at Currents to 1.0 A
- Sourced from Process 05
- This is a Pb-Free Device

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted) (Note 1, 2)

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	10	V
I _C	I _C Collector Current – Continuous		Α
T _J , T _{STG}	Operating and Storage Junction Temperature Range	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Note 3)

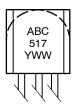
Symbol	Parameter	Max (Note 3)	Unit
P_{D}	Total Device Dissipation, T _A = 25°C	625	mW
	Derate Above 25°C	5.0	mW/°C
$R_{ heta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

3. PCB size: FR-4 76 x 114 x 1.57 mm 3 (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

1. Collector 2. Base 3. Emitter

TO-92 3 4.825x4.76 LEADFORMER CASE 135AR

MARKING DIAGRAM



BC517 = Specific Device Code A = Assembly Site Y = Year of Production WW = Work Week Number

ORDERING INFORMATION

Device	Package	Shipping		
BC517-D74Z	TO-92-3 LF	2000 Units / Fan-Fold		

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 2.0 mA, I _B = 0	30	_	-	V
V_{CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	40	_	-	V
V_{EBO}	Emitter-Base Breakdown Voltage	I _E = 100 nA, I _C = 0	10	_	_	V
I _{CBO}	Base Cut-Off Current	V _{CB} = 30 V, I _E = 0	_	_	100	nA
h _{FE}	DC Current Gain	V _{CE} = 2 V, I _C = 20 mA	30,000	_	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 100 mA, I _B = 0.1 mA	_	_	1	V
V _{BE} (on)	Base-Emitter On Voltage	I _C = 10 mA, V _{CE} = 5.0 V	_	_	1.4	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

BC517

TYPICAL PERFORMANCE CHARACTERISTICS

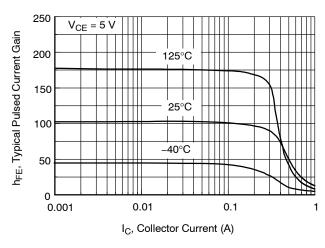
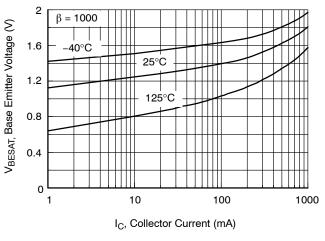


Figure 1. Typical Pulsed Current Gain vs. Collector Current

Figure 2. Collector – Emitter Saturation Voltage vs. Collector Current



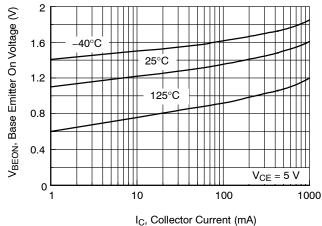
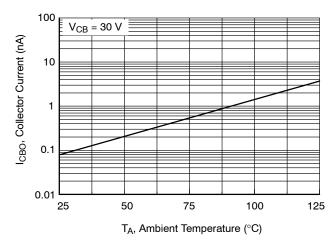


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

Figure 4. Base-Emitter On Voltage vs. Collector Current



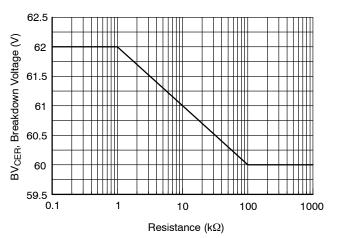


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

Figure 6. Collector-Emitter Breakdown Voltage with Resistance Between Emitter-Base

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

500

400

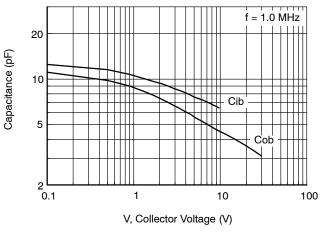
300

200

100

f_T, Gain Bandwidth Product (MHz)

V_{CE} = 5 V



1 10 20 50 100 150

Figure 8. Gain Bandwidth Product

vs. Collector Current



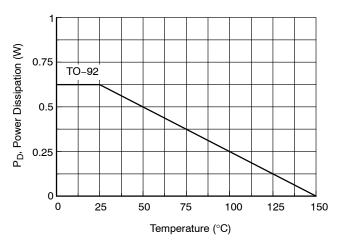


Figure 9. Power Dissipation vs. Ambient Temperature

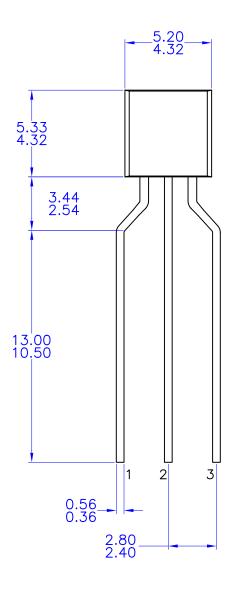


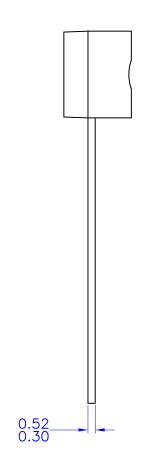


TO-92 3 4.83x4.76 LEADFORMED

CASE 135AR ISSUE O

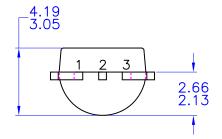
DATE 30 SEP 2016





NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994



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